TECHNICAL DATA
DATA SHEET 842, REV. A

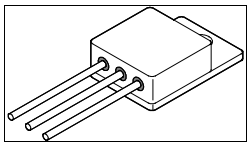
HERMETIC POWER SCHOTTKY RECTIFIER
Low Forward Voltage Drop
(200 V, 15 A)

Applications:

- **Switching Power Supply** • **Converters** • **Free-Wheeling Diodes** • **Polarity Protection Diode**

Features:

- **Soft Reverse Recovery at Low and High Temperature**
- **Low Forward Voltage Drop**
- **Low Reverse Leakage Current**
- **Low Power Loss, High Efficiency**
- **High Surge Capacity**
- **Guard Ring for Enhanced Durability and Long Term Reliability**
- **Guaranteed Reverse Avalanche Characteristics**



Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	200	V
Max. Average Forward Current (whole device)	$I_{F(AV)}$	50% duty cycle @T_C =100°C, rectangular wave form (Single & Doubler versions)	7.5	A
Max. Average Forward Current (whole device)	$I_{F(AV)}$	50% duty cycle @T_C =100°C, rectangular wave form (Common Cathode & Common Anode versions)	15	A
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	I_{FSM}	8.3 ms, half Sine pulse	75	A
Non-Repetitive Avalanche Energy (per leg)	E_{AS}	T_J = 25 °C, I_{AS} = 0.5 A L =60 mH	7.5	mJ
Repetitive Avalanche Current (per leg)	I_{AR}	I_{AS} decay linearly to 0 in 1 µs f limited by T_J max V_A=1.5V_R	0.5	A
Max. Junction Temperature	T_J	-	-65 to +200	°C
Max. Storage Temperature	T_{stg}	-	-65 to +200	°C

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg)	V_{F1}	@ 7.5 A, Pulse, T_J = 25 °C	1.01	V
	V_{F2}	@ 7.5 A, Pulse, T_J = 125 °C	0.88	V
Max. Reverse Current (per leg)	I_{R1}	@V_R = 200V, Pulse, T_J = 25 °C	0.18	mA
	I_{R2}	@V_R = 200V, Pulse, T_J = 125 °C	4.0	mA
Max. Junction Capacitance (per leg)	C_T	@V_R = 5V, T_C = 25 °C f_{SIG} = 1MHz, V_{SIG} = 50mV (p-p)	150	pF
Maximum Thermal Resis. (per leg)	$R_{\theta JC}$	-	2.73	°C/W
Max. Reverse Recovery Time	t_{rr}	I_F = 0.5 A, I_R = 1.0 A, I_{RM} = 0.25 A, T_J = 25 °C	25	nsec

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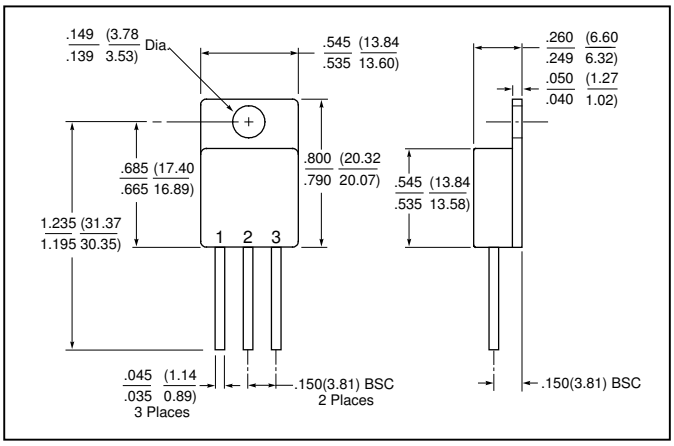
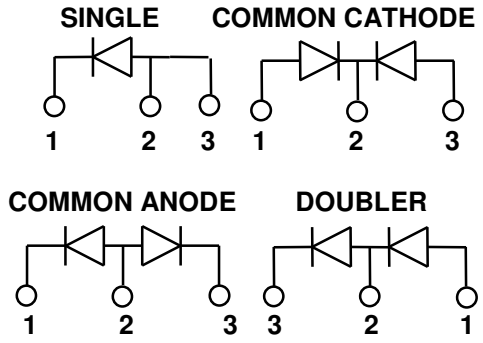
Mechanical Dimensions: In Inches / mm





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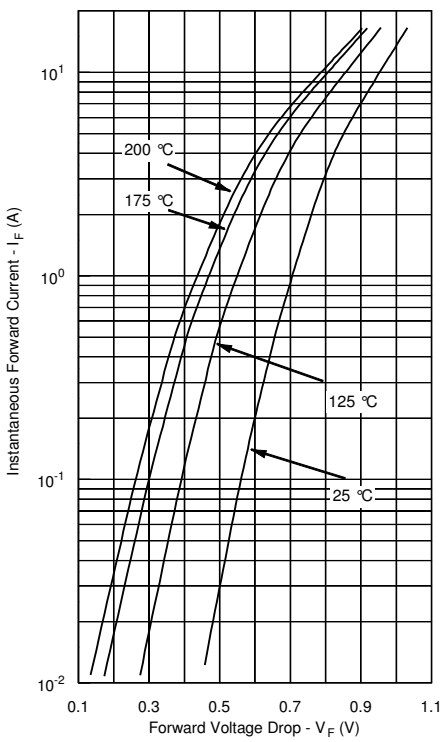
PINOUT TABLE

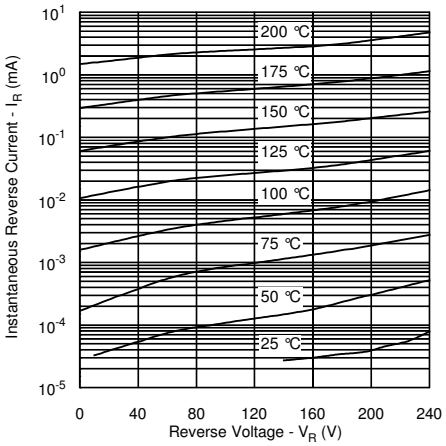
TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
DUAL RECTIFIER, COMMON CATHODE (P)	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER, COMMON ANODE (N)	CATHODE 1	COMMON ANODE	CATHODE 2
DUAL RECTIFIER, DOUBLER (D)	ANODE	ANODE/CATHODE	CATHODE

Note: The V_f curves shown are for the un-packaged die only.

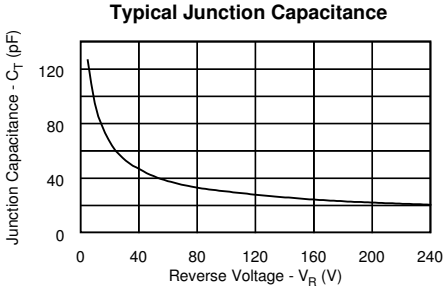
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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